H03F

AMPLIFIERS (measuring, testing <u>G01R</u>; optical parametric amplifiers <u>G02F</u>; circuit arrangement with secondary emission tubes <u>H01J 43/30</u>; masers, lasers <u>H01S</u>; control of amplification <u>H03G</u>; coupling arrangements independent of the nature of the amplifiers, voltage dividers <u>H03H</u>; amplifiers capable only of dealing with pulses <u>H03K</u>; repeater circuits in transmission lines <u>H04B 3/36</u>, <u>H04B 3/58</u>; application of speech amplifiers in telephonic communication <u>H04M 1/60</u>, <u>H04M 3/40</u>)

Definition statement

This place covers:

- Linear amplification, there being linear relationship between the amplitudes of input and output, and the output having substantially the same waveform as the input;
- Dielectric amplifiers, magnetic amplifiers, and parametric amplifiers when used as oscillators or frequency-changers;
- Constructions of active elements of dielectric amplifiers and parametric amplifiers if no provision exists elsewhere.

The user is otherwise referred to the IPC definitions for the individual main groups of <u>H03F</u> which follow hereinafter, although the following IPC groups are not used in the internal ECLA classification scheme. Subject matter covered by these groups is classified in the following ECLA groups: H03F1/44 covered by <u>H03F 1/42</u> H03F1/46 covered by <u>H03F 1/42</u> H03F3/18 covered by <u>H03F 3/30</u> H03F3/32 covered by <u>H03F 3/30</u> H03F7/06 covered by <u>H03F 7/00</u>

Provisions that are valid at a general level (e.g. of a kind appropriate to more than one of the main groups) are provided in the sections that follow.

The following list is intended to assist the user.

Relationships with other classification places

The structural association with elements coupled with amplifiers can be classified either in <u>H03F</u> or in the subclass covering the element (or in both the subclasses), depending on which aspect is more relevant.

In particular <u>H03F</u> units represented as "black boxes" in a specific application (e.g. a servo loop control circuit for a motor) are in general not classified in <u>H03F</u>, unless a specific technical effect which is relevant for <u>H03F</u> is achieved (e.g. linearity of amplification).

Components covered by specific subclasses (e.g. resistors, inductors, transmission lines, etc.):

- if relevant for their structural association with the amplifier are classified in H03F;
- if relevant only per se are not classified in <u>H03F</u>, but in the specific subclass.

References

Limiting references

This place does not cover:

Biomedical instrumentation amplifiers	<u>A61B 5/04</u>
Measuring, testing	<u>G01R</u>
Optical parametric amplifiers	<u>G02F</u>
Analog calculators	<u>G06G 7/12</u>
Musical instrument amplifiers (case of linear amplification)	<u>G10H</u>

Sound producing devices	<u>G10K</u>
Sense amplifiers	<u>G11C 7/06</u>
Variable transformers	H01F 29/14
Circuit arrangements with secondary emission tubes	<u>H01J 43/30</u>
Aerials	<u>H01Q</u>
Masers, lasers	<u>H01S</u>
Transference of modulation from one carrier to another	H03D 7/00
Amplifiers capable only of dealing with pulses, electronic switches, comparators, logic circuits, PWM signals	<u>H03K</u>
Analog transmitter circuits	<u>H04B 1/04</u>
Analog receiver circuits	<u>H04B 1/16</u>
Repeater circuits in transmission lines	H04B 3/36, H04B 3/58
Optical transmitters	<u>H04B 10/00</u>
Optical receivers	H04B10/158
Frequency-division multiplex system	<u>H04J 1/00, H04J 1/00</u>
Baseband systems	<u>H04L 25/00</u>
Digital transmitters	<u>H04L 27/04</u>
Digital receivers	H04L 27/06
Application of speech amplifiers in telephonic communication	H04M 1/60, H04M 3/40
Television systems with video amplifiers, IF amplifiers	H04N 5/148, H04N 9/647
Circuits for transducers, public address systems	H04R 3/00, H04R 27/00

Informative references

Attention is drawn to the following places, which may be of interest for search:

Semiconductors or other solid state devices	<u>H01L</u>
Nanotube transistors	<u>H01L 51/00</u>
Waveguides, resonators	<u>H01P</u>
Emergency protection circuit arrangements	<u>H02H</u>
AC/DC, DC/DC, AC/AC power converters	<u>H02M</u>
Generation of oscillations	<u>H03B</u>
Modulation	<u>H03C</u>
Demodulation	<u>H03D</u>
Control of amplification	<u>H03G</u>
Coupling arrangements independent of the nature of the amplifiers, voltage dividers, attenuators	<u>H03H</u>
Control of generators of electronic oscillations or pulses, e.g. phase locked loops	H03L
A/D and D/A converters, sigma delta modulators	<u>H03M</u>

Special rules of classification

As general remark, it must be noted that multiple classification symbols may be given. The philosophy is to classify documents in several sub-groups as the case may be, i.e. the classifier should not stop the classification task once that the first suitable EC symbol is found, but he should continue to assign EC symbols until all the aspects have been properly classified.

The subclass has a very large number of related technical areas, e.g.:

• "application" fields such as transmitters, receivers, voltage regulators, multimedia devices, etc.

Indexing Code orthogonal classification

In addition to one or more classification symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to orthogonal classification (H03F 2200/03 - H03F 2200/555), i.e. covering aspects which are spanning over one or more groups, should be allocated for the following ranges:

H03F 1/00 H03F 1/565

H03F 3/181 H03F 3/213

H03F 3/24 H03F 3/72

Vacuum tube amplifiers classification

The following IPC groups, which are mostly related to discharge tube amplifiers or general type amplifiers, are used to classify circuit topologies based also on vacuum tubes, valve amplifiers, due to historical reasons (see vacuum tube amplifier in the "Glossary of terms" section below):

H03F 1/04 H03F 1/07 H03F 1/13 H03F 1/16 H03F 1/20 H03F 1/24 H03F 1/28 H03F 1/33 H03F 1/36 H03F 1/40 H03F 1/50 H03F 1/54 H03F 3/02 H03F 3/181 H03F 3/189 H03F 3/22 H03F 3/28 H03F 3/36

H03F 3/40

H03F 3/44

H03F 3/48

H03F 3/52

H03F 3/64

Glossary of terms

In this place, the following terms or expressions are used with the meaning indicated:









Single Ended Push Pull	Push pull amplifier wherein the output terminals of the amplifying elements are tied together as a single ended output without additional balun elements.
Differential amplifier	$V_{+} \bullet \downarrow V_{\text{S}+} \\ V_{-} \bullet \downarrow V_{\text{S}-} \\ V_{\text{S}-} \\ \text{the basic differential amplifier amplifies the difference between two voltages; the output voltage is determined according to the following equation: V_{\text{out}} = A_{\text{d}}(V_{\text{in}}^{+} - V_{\text{in}}^{-}) + A_{\text{c}}\left(\frac{V_{\text{in}}^{+} + V_{\text{in}}^{-}}{2}\right) \\ \text{wherein Ac is the common mode gain and Ad is the differential mode gain.}$
Common mode rejection ratio	the common-mode rejection ratio (CMRR) indicates the ability of the amplifier to accurately cancel voltages that are common to both inputs. The common-mode rejection ratio is defined as: $\overline{\text{CMRR} = 10 \log_{10} \left(\frac{A_{\text{d}}}{A_{\text{cm}}}\right)^2 = 20 \log_{10} \left(\frac{A_{\text{d}}}{ A_{\text{cm}} }\right)}$

Vacuum tube amplifier	160 Volts
	Putput
	^{ground} Until the invention of the transistor
	in 1947, all practical amplifiers were made using Vacuum tubes, which rely on thermionic emission of electrons from a hot filament
	(cathode), that then travel through a vacuum toward a collecting
	John Ambrose Fleming while working for the Marconi Company
	In London in 1904 and named the diode, as it had two electrodes. The diode conducted electricity in one direction only and was used
	as a radio detector and a rectifier. In 1906 Lee De Forest added a third electrode (grid) and invented the first electronic amplifying
	device, the triode, which he named the Audion. This additional
	and anode. (drawing and historical background extracted from
Common emitter/equires /	Wikipedia).
cathode	
	Amplifying device wherein the emitter/source/
	cathode terminal is connected to RF ground/earth and the input (control) terminal is the base/gate/grid.
Common base/gate /grid	
	R _c
	P C Vout
	<i>V</i> _{in} A mplifying device wherein the base/gate/grid
	terminal is connected to RF ground/earth and the input (control) terminal is the emitter/source/cathode.
Cascade coupling	
	Two or more amplifying devices wherein the
	terminal of the second device in order to form a chain of amplifying
	elements.

Cascode coupling	A cascade coupling of a common emitter/ source/cathode amplifying device followed by a common base/ gate/grid amplifying device.
Common collector/drain/anode, i.e. Emitter/source /cathode follower	V_{in} V_{in} V_{out} V_{out} V_{out} K_E K_E V_{out} K_E V_{out} K_E K_E K_E V_{out} K_E K_E K_E K_E V_{out} K_E $K_$
Emitter/Source degeneration	$V_{in}^{K} \xrightarrow{R_{C}} V_{out}$ $V_{in}^{B} \xrightarrow{R_{E}} V_{out}$ Amplifying device in common emitter/source/ cathode configuration wherein an additional element (degeneration element) is connecting the emitter/source/cathode terminal with the RF ground/earth.
Darlington amplifier	Bipolar transistors are in Darlington configuration when they have the collector terminals tied together and the emitter of the first transistor is connected to the base of the second transistor so that the current gain of the composite transistor is increased.





Pseudo differential amplifier	* ****
	$(l_1 + l_2) / 2$ $(l_1 + l_2) / 2$
	\odot
	$(l_2 - l_1)/2$ $(l_1 - l_2)/2$
	$ \begin{array}{c c} V_{a} & 1_{1} & 1_{2} & V_{b} \\ \hline \circ & & & \downarrow \\ \end{array} \end{array} $
	differential amplifier consists of two amplifying transistors, wherein
	the BJT emitters (or FET sources, or valve cathodes) are not
	connected together but directly coupled to the ground. Thus, since
	difference between gate signals Va, Vb, the configuration acts as
	a differential transconductance amplifier (drawing extracted from
	US2009115461).
Reflex amplifier	56
	24
	22 20 23
	$ \begin{array}{c} 3^{3} \\ -3^{3} \\ -3^{3} \end{array} $
	12 - 41 - 42 $50 - 52$ 57
	32 - 56 - 51 - 51 - 51 - 51 - 51 - 51 - 51
	▼ ₹ ▼ In a basic reflex amplifier an AC input signal is amplified and then rectified and using the
	same circuit elements, the fed back resultant rectified DC signal
	is again amplified. The reflex circuit thus achieves two stages
	extracted from US2863066).







Note: all the drawings of the present section, when not explicitly indicated, have been extracted from Wikipedia.

Synonyms and Keywords

RF	Radio Frequency
HF	High Frequency, Hoch-Frequenz (German). Haute Fréquence (French)
NF (German)	Nieder-Frequenz (German)
NF	Noise Figure
LF	Low Frequency

In patent documents, the following abbreviations are often used:

BF (French)	Basse Fréquence (French)
LNA	Low Noise Amplifier
MMIC	Microwave Monolithic Integrated Circuit
IC	Integrated Circuit
OP-AMP	Operational Amplifier
FET	Field Effect Transistor
TEC (French)	Transistor à Effet de Champ (French)
AC	Alternate Current
DC	Direct Current
DAT	Distributed Active Transformer
SEPP	Single Ended Push Pull
BALUN	Balanced/Unbalanced or Unbalanced/Balanced
EMI	Electromagnetic Interference
ESD	Electro Static Discharge
TD	Time Domain
PD	Predistorter
BIFET	Bipolar and Field Effect Transistor
CMMR	Common-Mode Rejection Ratio
CCCS	Current Controlled Current Source
CCVS	Current Controlled Voltage Source
VCVS	Voltage Controlled Voltage Source
VCCS	Voltage Controlled Current Source
TIA	Trans-Impedance Amplifier
ΟΤΑ	Operational Transconductance Amplifier
TWT	Travelling Wave Tube
PA	Power Amplifier
DPA	Doherty Power Amplifier
MMPA	Multi-Mode Power Amplifier
TWTA	Travelling Wave Tube Amplifier
LTP	Long Tailed Pair
EER	Envelope Elimination and Restoration
ET	Envelope Tracking
BTL	Bridged Tied Load

H03F 1/00

Details of amplifiers with only discharge tubes, only semiconductor devices or only unspecified devices as amplifying elements

Definition statement

This place covers:

Details of amplifiers with only discharge tubes, only semiconductor devices or only unspecified devices as amplifying elements, wherein said details are addressing a specific technical effect for the amplification:

Raise the efficiency

Reduce detrimental influences of internal impedances of the amplifying elements

Reduce influence of noise generated by amplifying elements

Reduce influence of variations of temperature or supply voltage or other physical parameters

Reduce non-linear distortion (except when using negative feedback)

Negative feedback with or without positive feedback

Positive feedback without negative feedback

Bandwidth extension

Protection

Modification of input or output impedances

The technical effect is specified according to the IPC definitions for the individual subgroups of <u>H03F 1/00</u> which follow hereinafter.

Special rules of classification

A document may be temporarily allocated in the main group <u>H03F 1/00</u> only for EPO internal circulation, e.g. to receive it from neighbouring field classifiers via the classification code.

H03F 1/02

Modifications of amplifiers to raise the efficiency, e.g. gliding Class A stages, use of an auxiliary oscillation

Definition statement

This place covers:

Modifications of amplifiers to raise the efficiency, wherein said modification comprises the following techniques:

dynamic bias control based on the input/output signal

supply control based on the input/output signal

selection of one or more amplifiers from a plurality of amplifier

reduction of the number of DC current paths

use of particular circuit topologies, e.g. Doherty amplifier, LINC Amplifier

use of discharge tube amplifiers acting also as modulators.

References

Limiting references

This place does not cover:

Transmitter circuits with power amplifiers having gain or transmission	H04B 2001/0416,
power control, with means for improving efficiency	H04B 2001/045

Informative references

Attention is drawn to the following places, which may be of interest for search:

Amplitude modulation by converting angle modulation to amplitude modulation	<u>H03C 1/50</u>
Gain control details, gain control by varying the supply voltage, gain control dependent on the supply voltage	H03G 1/00, H03G 3/004, H03G 3/007
Transmission power control	H04W 52/04

H03F 1/08

Modifications of amplifiers to reduce detrimental influences of internal impedances of amplifying elements (wide-band amplifiers with inter-stage coupling networks incorporating these impedances <u>H03F 1/42</u>; eliminating transit-time effects in vacuum tubes <u>H01J 21/34</u>)

Definition statement

This place covers:

Modification of amplifiers to achieve frequency stabilisation or signal isolation among amplifying stages, wherein said modification comprises the following techniques:

use of particular circuit topologies, e.g. transimpendance amplifier, cascode amplifier

use of amplifying elements with multiple electrode connections

use of attenuating means

use of neutralising means, e.g. Miller effect compensation circuitry, pole/zero cancellations in the transfer function

use of distributed coupling

References

Limiting references

This place does not cover:

Eliminating transit-time effects in vacuum tubes	<u>H01J 21/34</u>
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Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Differential cascode amplifiers, differential folded cascode amplifiers	H03E 3/45089
	H03F 3/45094
	H03F 3/45103.
	H03F 3/45107.
	H03F 3/45116.
	H03F 3/45121.
	H03F 3/4513.
	H03F 3/45134.
	H03F 3/45143,
	H03F 3/45147,
	H03F 3/45156,
	H03F 3/45161,
	H03F 3/45188,
	H03F 3/45192,
	H03F 3/45201,
	H03F 3/45206,
	H03F 3/45215,
	H03F 3/45219,
	H03F 3/45228,
	H03F 3/45233,
	H03F 3/45242,
	H03F 3/45246,
	H03F 3/4526,
	H03F 3/45255,
	H03F 3/45286,
	<u>H03F 3/45291,</u>
	<u>H03F 3/453,</u>
	<u>H03F 3/45304,</u>
	<u>H03F 3/45313,</u>
	<u>H03F 3/45318,</u>
	<u>H03F 3/45327</u> ,
	<u>H03F 3/45331</u> ,
	<u>H03F 3/4534,</u>
	<u>H03F 3/45345,</u>
	<u>H03F 3/45354,</u>
	<u>H03F 3/45358,</u>
	<u>H03F 3/45385</u> ,
	<u>H03F 3/4539</u> ,
	<u>103F 3/45399,</u>
	103F 3/43403,
	103F 3/43412,
	H03E 3/45417,
	H03F 3/45420,
	H03F 3/45430
	H03F 3/45443
	H03F 3/45452
	<u>H03F 3/45457</u>
Transmitter circuits with power amplifiers having gain or transmission	H04B 2001/0416.
power control, with means for improving efficiency	H04B 2001/045
Optical receivers with arrangements for optimising the preamplifier	H04B 10/693

Informative references

Attention is drawn to the following places, which may be of interest for search:

Wide-band amplifiers with inter-stage coupling networks incorporating these impedences	H03F 1/42
Distributed amplifiers using coupling networks with distributed constants	H03F 3/605
Gain control in emitter coupled or cascode amplifiers	H03G 1/0023
Modifications of control circuit to reduce distortion caused by control	<u>H03G 1/04</u>
Muting circuits	<u>H03G 3/26, H03G 3/34</u>
Amplitude limiters	H03G 11/00

Glossary of terms

In this place, the following terms or expressions are used with the meaning indicated:

Current steering cascode	cascode amplifier formed by at least two common gate transistors
	which are both coupled to the drain terminal of the input common
	source transistor, in order to steer the current at that terminal
	among different paths.

Synonyms and Keywords

In patent documents, the following words/expressions are often used with the meaning indicated:

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H03F 1/26

Modifications of amplifiers to reduce influence of noise generated by amplifying elements

References

Limiting references

This place does not cover:

Modifications of amplifiers to reduce influence of variations of supply voltage in case of switching on or off of a power supply, i.e. popping noise reduction	<u>H03F 1/305</u>
Constructional modification of discharge tubes amplifiers	H01J 23/11

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Chopper amplifiers	H03F 3/38
Transmitter circuits with means for limiting noise	H04B 1/0475

H03F 1/30

Modifications of amplifiers to reduce influence of variations of temperature or supply voltage {or other physical parameters (in differential amplifiers H03F 3/45479)}

Definition statement

This place covers:

Modifications of amplifiers to reduce influence of variations of temperature or supply voltage, or other physical parameters, wherein said modifications comprise:

bias stabilisation circuits

drifting protection circuits

using a switching device and eventually digital means

case of switching on or off a power supply

case of push-pull configuration

References

Limiting references

This place does not cover:

Differential amplifiers characterised by the way of common mode signal	H03F 3/45479
rejection	

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Push-pull amplifiers	<u>H03F 3/26</u>
Single-ended push-pull (SEPP)	H03F 3/30

Informative references

Attention is drawn to the following places, which may be of interest for search:

Voltage, current regulators	<u>G05F 1/10, G05F 3/02</u>
Muting circuits	H03G 3/26, H03G 3/34

Glossary of terms

In this place, the following terms or expressions are used with the meaning indicated:

Popping noise	audible noise which is present when switching on or off the power
	supply

Synonyms and Keywords

In patent documents the following expressions are often used as synonyms:

Popping noise pop effect, plop noise, clic	Popping noise	pop effect, plop noise, clic
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H03F 1/32

Modifications of amplifiers to reduce non-linear distortion (by negative feedback H03F 1/34)

Definition statement

This place covers:

Modifications of amplifiers to reduce non-linear distortion, wherein said modifications comprise:

using feedforward circuits

using predistortion circuits, which are implemented with feedback, or via multiple paths, or in audio amplifiers, or with nonlinear elements, or acting on cartesian and polar parameters

case of differential amplifiers

case of single ended push pull amplifiers

References

Limiting references

This place does not cover:

Modifications of amplifiers to reduce non-linear distortion by negative	H03F 1/34
feedback	

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Analog transmitter circuits with power amplifiers with linearisation using predistortion and using feed-forward	<u>H04B 2001/0425,</u> H04B 2001/0441
Analog transmitter circuits with means for limiting distortions	<u>H04B 1/0483,</u> H04B 1/0475
Digital transmitters using predistortion	H04L 27/367

Special rules of classification

Indexing Code orthogonal classification

In addition to one or more classification symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to orthogonal classification (<u>H03F 2201/3203</u> - <u>H03F 2201/3236</u>), i.e. covering aspects which are spanning over one or more EC subgroups, should be allocated for the following sub-groups range: <u>H03F 1/32</u> - <u>H03F 1/3241</u>.

H03F 1/34

Negative-feedback-circuit arrangements with or without positive feedback (<u>H03F 1/02</u> - <u>H03F 1/30</u>, <u>H03F 1/38</u> - <u>H03F 1/50</u>, <u>H03F 3/50</u> take precedence; {for rejection of common mode signals <u>H03F 3/45479</u>})

Definition statement

This place covers:

Negative-feedback-circuit arrangements with or without positive feedback, wherein said arrangements comprises:

adaptations for reducing the non-linear distortion

hybrid or directional couplers

transformers.

References

Limiting references

This place does not cover:

Differential amplifiers for the rejection of common mode signals	H03F 3/45479
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Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Analog transmitter circuits with means for limiting distortions	H04B 1/0483,
	H04B 1/0475

H03F 1/38

Positive-feedback circuit arrangements without negative feedback

References

Informative references

Attention is drawn to the following places, which may be of interest for search:

Generation of oscillation	<u>H03B</u>

H03F 1/42

Modifications of amplifiers to extend the bandwidth

Definition statement

This place covers:

Modifications of amplifiers to extend the bandwidth, wherein the modifications comprise:

periodic amplifiers

aperiodic amplifiers, i.e. wherein aperiodic means that there is no resonant circuit present.

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Pulse shaping by amplifying	<u>H03K 5/02</u>
Analog transmitter circuits with means for limiting distortions	H04B 1/0483, H04B 1/0475
Optical receivers with bandwidth control	H04B 10/6932

Glossary of terms

In this place, the following terms or expressions are used with the meaning indicated:

Inductive peaking	an inductor is placed in the amplifying circuit to extend the
	bandwidth of amplification.

H03F 1/52

Circuit arrangements for protecting such amplifiers {(monitoring arrangements <u>G01R 31/28</u>; increasing reliability in communication systems, e.g. using redundancy <u>H04B 1/74</u>)}

Definition statement

This place covers:

Circuit arrangements for protecting such amplifiers, wherein the arrangements comprises:

using redundant amplifying elements

using protective devices, e.g. diodes.

References

Limiting references

This place does not cover:

Protection from temperature drifting	<u>H03F 1/30</u>
Vacuum tube testing	<u>G01R 31/25</u>

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Monitoring arrangements	<u>G01R 31/28</u>
Analog transmitter details for increasing reliability	<u>H04B 1/74</u>

Informative references

Attention is drawn to the following places, which may be of interest for search:

Emergency protective circuit arrangements <u>H02H 7/20</u>
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Over voltage protection in integrated circuits	<u>H02H 9/046</u>
Frequency-division multiplex system with monitoring arrangements	<u>H04J 1/16, H04J 1/16</u>

H03F 1/56

Modifications of input or output impedances, not otherwise provided for

Definition statement

This place covers:

Modifications of input or output impedances, not otherwise provided for, wherein said modifications may comprise:

matching and tuning circuits which are specifically designed for RF amplifiers

circuit adaptations in class E,F,E/F amplifiers.

References

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

High frequency amplifiers	<u>H03F 3/189</u>
Switching amplifiers in general	<u>H03F 3/217</u>
Class E amplifiers	<u>H03F 3/2176</u>
Amplifiers in which coupling networks have distributed constants	H03F 3/60

Informative references

Attention is drawn to the following places, which may be of interest for search:

Matching with passive networks	<u>H03H 7/38</u>
Matching with active networks	<u>H03H 11/28</u>

H03F 3/00

Amplifiers with only discharge tubes or only semiconductor devices as amplifying elements

Definition statement

This place covers:

Electronic amplifiers based on tubes or semiconductors.

Amplifiers are classified according to topology (e.g., push-pull, emitter follower, differential) and/or according to use (e.g., LF, HF) and/or according to the amplifying element (e.g., tubes, tunnel diodes) and/or according to special functionality (e.g., multi-channel amplifiers, gated amplifiers).

Amplifiers with both tubes and semiconductors are classified in H03F 5/00.

Amplifiers based on other amplification principles such as magnetic, dielectric, mechanical/acoustic, superconductivity, etc., are classified in subgroups <u>H03F 7/00-H03F 21/00</u>.

Special rules of classification

A document may be temporarily allocated in the main group <u>H03F 3/00</u> only for EPO internal circulation, e.g. to receive it from neighbouring field classifiers via the classification code.

H03F 3/005

{using switched capacitors, e.g. dynamic amplifiers; using switched capacitors as resistors in differential amplifiers (H03F 3/45 takes precedence)}

Definition statement

This place covers:

Amplifiers with switched capacitors used as synthesized resistors.

References

Limiting references

This place does not cover:

Amplifiers with charge pump- or other switched capacitor based power supplies	<u>H03F 1/02</u>
Modulator/demodulator (chopper) amplifiers	H03F 3/38
Chopper/auto-zero amplifiers for offset/noise reduction in differential amplifiers	<u>H03F 3/45</u>

Informative references

Attention is drawn to the following places, which may be of interest for search:

H03F 3/02

with tubes only (subsequent sub-groups take precedence)

References

Limiting references

This place does not cover:

	4
Travelling wave tube amplifiers	<u>H03F 3/58</u>

H03F 3/08

controlled by light

Definition statement

This place covers:

Amplifiers controlled by light, that is, for optically generated or transferred signals, e.g., transimpedance amplifiers for fiber optic links, optical isolation amplifiers.

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Optical receivers H04B10/158	
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H03F 3/082

{with FET's (H03F 3/085 takes precedence)}

Definition statement

This place covers:

Amplifiers controlled by light, wherein the amplifier comprises FETs, e.g., JFET or CMOS transimpedance amplifiers for fiber optic links.

H03F 3/085

{using opto-couplers between stages}

Definition statement

This place covers:

Amplifiers controlled by light, wherein the amplifier comprises optically coupled stages, e.g., optical isolating amplifiers.

H03F 3/087

{with IC amplifier blocks (H03F 3/085 takes precedence)}

Definition statement

This place covers:

Amplifiers controlled by light, wherein the amplifier has functional units such as op-amps, i.e., not showing transistor level circuit details.

H03F 3/10

with diodes {(parametric amplifiers H03F 7/00)}

Definition statement

This place covers:

Amplifiers using diodes as an amplifying element, e.g., negative resistance diodes such as Gunn, IMPATT, Esaki (tunnel) diodes.

References

Limiting references

This place does not cover:

Switching amplifiers with freewheeling diodes	H03F 3/217
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H03F 3/12

with Esaki diodes

Definition statement

This place covers: Amplifiers using Esaki (tunnel) diodes as an amplifying element.

H03F 3/14

with amplifying devices having more than three electrodes or more than two PN junctions

Definition statement

This place covers:

Amplifiers with semiconductor amplifying devices having more than three electrodes, e.g., dual-gate MOSFETs, back-gate controlled MOSFETs, multi-emitter/collector BJTs. Note: by semiconductor amplifying devices is understood transistors; opamps and the like are not included, even if they have more than three terminals. Cascode amplifiers using dual-gate MOSFETs are classified in H03F 1/223.

H03F 3/16

with field-effect devices

Definition statement

This place covers:

Amplifiers with semiconductor field-effect amplifying devices, e.g., MOSFETs, JFETs, MESFETs.

H03F 3/165

{with junction-FET's}

Definition statement

This place covers:

Amplifiers with semiconductor junction field-effect amplifying devices, e.g., JFETs, MESFETs (but not MOSFETs).

H03F 3/181

Low frequency amplifiers, e.g. audio preamplifiers

Definition statement

This place covers:

Low frequency amplifiers, in most cases which are suitable for amplification of audio signals.

References

Informative references

Attention is drawn to the following places, which may be of interest for search:

Switching amplifiers	H03F 3/217
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Gain control in low frequency amplifiers	H03G 3/3005, H03G 7/002, H03G 7/007, H03G 3/3089
Circuits for loudspeakers, microphones	<u>H04R 3/00</u>

H03F 3/189

High frequency amplifiers, e.g. radio frequency amplifiers

Definition statement

This place covers:

High frequency amplifiers, e.g. radio frequency amplifiers, as detailed circuits or integrated circuit blocks.

References

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Amplifiers in which coupling networks have distributed constant	<u>H03F 3/60</u>
IF amplifier circuits specially adapted for B&W TV	<u>H04N 5/4446</u>

Informative references

Attention is drawn to the following places, which may be of interest for search:

Switching amplifiers	H03F 3/217
High frequency adaptations of semiconductors	<u>H01L 23/66</u>
Gain control in high frequency amplifiers, bandpass amplifiers	<u>H03G 3/3036,</u> <u>H03G 3/3052</u>

Synonyms and Keywords

In patent documents, the following abbreviations are often used:

HBT	Heterojunction Bipolar Transistor
НЕМТ	High Electron Mobility Transistor

H03F 3/20

Power amplifiers, e.g. Class B amplifiers, Class C amplifiers (H03F 3/26 - H03F 3/30 take precedence)

Definition statement

This place covers:

Power amplifiers in general. e.g. class B amplifiers, Class C amplifiers, Class D amplifiers, Class E amplifiers, Class F amplifiers, Class G amplifiers, Class H amplifiers, Class S amplifiers, or combination of power amplifiers, or integrated circuits wherein the circuit topology is based on lumped elements.

Limiting references

This place does not cover:

Push pull amplifiers	<u>H03F 3/26</u>
Single ended push pull amplifiers	<u>H03F 3/30</u>
Combination of amplifiers in which coupling networks have distributed constant	<u>H03F 3/602</u>

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Multi-channel amplifiers	H03F 3/68
Analog transmitters	<u>H04B 1/02</u>
Digital transmitters	<u>H04L 27/04</u>

Special rules of classification

Documents which are addressing a power amplifier in general are usually not classified in this subgroup, but are allocated to the corresponding subgroups:

H03F 3/21

H03F 3/211

H03F 3/213

H03F 3/217

H03F 3/22

H03F 3/24

Indexing Code deep-indexing classification

In addition to one or more classification symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to deep-indexing classification (<u>H03F 2203/21103</u> - <u>H03F 2203/21196</u>), i.e. covering embodiment aspects, should be allocated for the following sub-group: <u>H03F 3/211</u>

H03F 3/217

Class D power amplifiers; Switching amplifiers

Definition statement

This place covers:

Amplifiers using switches as amplifying elements, e.g., class D audio amplifiers, class E, class F, class S RF amplifiers, as well as control circuitry such as PCM-PWM conversion etc.

Limiting references

This place does not cover:

Amplifiers with switched-mode (e.g., tracking) power supplies	H03F 1/02
Chopper/auto-zero amplifiers	<u>H03F 3/38; H03F 3/45</u>
Gated amplifiers	H03F 3/72

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

MRI gradient amplifiers	<u>G01R 33/3852</u>
DC-AC converters	<u>H02M 3/00</u>
Deaf-aid sets	<u>H04R 25/00</u>
Stereophonic systems	<u>H04S</u>

Special rules of classification

Multiple classification symbols may be given, e.g., a stereo full-bridge class D audio power amplifier with protection means and anti pop-noise means would be classified in H03F 3/68, H03F 3/2173, H03F 1/52, H03F 1/305, and possibly also somewhere in H04S. A class D MRI gradient amplifier would be classified in both G01R 33/3852 and H03F 3/217. An RF amplifier with a class D amplifier used as a tracking power supply (aka class S) would be classified in the relevant H03F 1/02 sub-group, as well as in H03F 3/217 (provided that the class D amplifier is shown in some detail), and possibly also in H03F 3/189, for example.

H03F 3/2171

{with field-effect devices (H03F 3/2173 - H03F 3/2178 take precedence)}

Definition statement

This place covers:

Switching amplifiers using FET switches as amplifying elements.

H03F 3/2173

{of the bridge type}

Definition statement

This place covers: Switching amplifiers with half- or full-bridges.

H03F 3/2175

{using analogue-digital or digital-analogue conversion (H03F 3/2173 takes precedence)}

Definition statement

This place covers:

Switching amplifiers for digital input signals, or having explicit ADCs or DACs.

H03F 3/2176

{Class E amplifiers}

Definition statement

This place covers: Class E RF amplifiers.

References

Limiting references

This place does not cover:

Class F RF amplifiers (see the "Glossary of terms" section above). These are classified in other relevant $\frac{H03F 3/217}{1000}$ subgroups.

H03F 3/2178

{using more than one switch or switching amplifier in parallel or in series (H03F 3/2173, H03F 3/2175 take precedence)}

Definition statement

This place covers:

Switching amplifiers with one or more switches (e.g., segmented transistors in RF amplifiers) or output stages (such as in staggered phase class D amplifiers) in parallel or in series, cooperating to produce a common output signal.

References

Limiting references

This place does not cover:

Combinations of a switching amplifier and a linear amplifier to produce a single output signal (but a $\frac{H03F 3}{217}$ sub-group should still be given, by virtue of the switching amplifier).	<u>H03F 3/211</u>
Multi-channel amplifiers	<u>H03F 3/68</u>

H03F 3/22

with tubes only (H03F 3/24 takes precedence)

Definition statement

This place covers:

Power amplifiers with tubes (thermionic valves only).

References

Limiting references

This place does not cover:

Tube power amplifiers for radio transmitters	<u>H03F 3/24</u>
Tube push-pull amplifiers (two tubes connected to either side of a transformer primary with a center tap connected to a supply voltage and driven out of phase).	<u>H03F 3/28</u>
Tube single-ended push-pull amplifiers (tubes connected in series across two supply rails and the output signal taken at the node common to the tubes)	<u>H03F 3/30</u>

H03F 3/26

Push-pull amplifiers; Phase-splitters therefor (duplicated single-ended pushpull arrangements or phase-splitters therefor <u>H03F 3/30</u>)

Definition statement

This place covers:

Push-pull amplifiers (see the push-pull configuration in the "Glossary of terms" section above) and phase-splitters therefor, i.e. the phase splitter circuitry which is suitable for driving them.

References

Limiting references

This place does not cover:

Duplicated single-ended push-pull arrangements or phase-splitters therefor	<u>H03F 3/30</u>
Single-ended sense amplifiers	<u>G11C 7/067</u>

H03F 3/30

Single-ended push-pull {[SEPP]} amplifiers {(single-ended sense amplifiers <u>G11C 7/067</u>)}; Phase-splitters therefor

Definition statement

This place covers:

Single-ended push-pull amplifiers (see the SEPP configuration in the "Glossary of terms" section above) and phase-splitters therefor, i.e. the phase splitter circuitry which is suitable for driving them.

Limiting references

This place does not cover:

Switching amplifiers	H03F 3/217
Single-ended sense amplifiers	<u>G11C 7/067</u>

Special rules of classification

It must be noted that the expression "common drain output", which is present in the definition of subgroup H03F 3/301, relates to a common drain configuration for the output transistors (see the "Glossary of terms" section above), therefore it relates to the source terminals of the output transistors being tied together to form the output terminal.

Similar consideration applies for the expression "common source output", which is present in the definition of subgroup <u>H03F 3/3022</u>, and which relates to a common source configuration of the output transistors (see the "Glossary of terms" section above), i.e. the drain terminals of the output transistors being tied together to form the output terminal.

Furthermore, in the following subgroups the expression "symmetrical driving of the end stage" is present:

H03F 3/3016

H03F 3/3028

H03F 3/305

H03F 3/3059

H03F 3/3064

H03F 3/3076

From a circuital topology point of view, it relates to the presence of symmetry in the driving stage circuitry of the SEPP, i.e. if the driving signal path for one of the output transistor has the same/ corresponding/complementary elements of the driving signal path of the other output transistor.



As clarifying example the following circuit topology is shown.

Example of SEPP with symmetrical driving of the end stage (drawing extracted from US2002109548).

Mostly of the times the presence of symmetry can be easily detected on the circuit topology by considering a virtual axis (see the dotted line "Symmetry axis" in the drawing above) passing through the output terminal to determine two sub-circuits which are located above and below said axis, respectively, and by examining the similarities/corresponding elements among the two sub-circuits.

If no symmetry is detected then the SEPP circuit is of the type having "asymmetrical driving of the end stage" and it has to be classified in one of the following subgroups:

H03F 3/3011 H03F 3/3023 H03F 3/3037 H03F 3/3042 H03F 3/3045 H03F 3/3057 H03F 3/3062 H03F 3/3067 H03F 3/3071

H03F 3/3088

Furthermore, it must be noted that, when two SEPPs are configured as class B or AB bridges, they are classified in <u>H03F 3/3081</u> and when they are implemented with FETs they are classified in <u>H03F 3/3061</u>. Switching amplifiers in bridge configuration are classified in <u>H03F 3/2173</u>.

Indexing Code orthogonal classification

In addition to one or more EC symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to orthogonal classification (<u>H03F 2203/30003</u> - <u>H03F 2203/30156</u>), i.e. covering aspects which are spanning over one or more EC subgroups, should be allocated for this subgroup.

H03F 3/34

Dc amplifiers in which all stages are dc-coupled (H03F 3/45 takes precedence)

Definition statement

This place covers:

DC amplifiers which are formed by IC blocks, semiconductors or tubes, in which all the amplifying stages are DC coupled, e.g. without using capacitive or switching elements, which are not specific for RF amplifiers or audio amplifiers and which have circuit topologies that are not related to other <u>H03F</u> classification symbols.

References

Limiting references

This place does not cover:

Differential amplifiers	H03F 3/45

References out of a residual place

Examples of places in relation to which this place is residual:

Low frequency amplifiers	<u>H03F 3/181</u>
High frequency amplifiers	<u>H03F 3/189</u>
Power amplifiers	H03F 3/20

Informative references

Attention is drawn to the following places, which may be of interest for search:

DC current or voltage control circuits	G05F 3/02

H03F 3/38

Dc amplifiers with modulator at input and demodulator at output; Modulators or demodulators specially adapted for use in such amplifiers ({switched capacitor amplifiers H03F 3/005}; modulators in general H03C; demodulators in general H03D; amplitude modulation of pulses in general H03K 7/02; amplitude demodulation of pulses in general H03K 9/02)

Definition statement

This place covers:

DC amplifiers wherein only the AC signal is passed through the amplifying units, the DC signal is decoupled via switching elements, e.g. see the Chopper amplifier configuration in the "Glossary of terms" section above.

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Switched capacitor amplifiers	H03F 3/005
Switching amplifiers	H03F 3/217
Differential amplifiers	H03F 3/45
Arrangements for measuring bio-electric currents or voltages	<u>A61B 5/04</u>
Arrangements for measuring currents or voltages or for indicating presence or sign thereof by using conversion of dc into ac	<u>G01R 19/18</u>

Informative references

Attention is drawn to the following places, which may be of interest for search:

Modifications of amplifiers to reduce influence of noise generated by amplifying elements	<u>H03F 1/26</u>
Modulation	<u>H03C</u>
Demodulation	<u>H03D</u>
Switched capacitor networks	<u>H03H 19/004</u>
Amplitude modulation of pulses in general	<u>H03K 7/02</u>
Amplitude demodulation of pulses in general	<u>H03K 9/02</u>

H03F 3/42

Amplifiers with two or more amplifying elements having their dc paths in series with the load, the control electrode of each element being excited by at least part of the input signal, e.g. so-called totem-pole amplifiers

Definition statement

This place covers:

In most cases totem-pole amplifiers, see the "Glossary of terms" section above, which are implemented via semiconductor elements or tubes.

H03F 3/45

Differential amplifiers (differential sense amplifiers G11C 7/062)

Definition statement

This place covers:

Differential amplifiers in general and characterised by the technology used, the circuit topologies, and the way that the common mode signals are rejected.

Limiting references

This place does not cover:

Measuring currents or voltages from sources with high internal resistance by means of measuring circuits with high input impedance, e.g. OP- amplifiers	<u>G01R 19/0023</u>
Operational amplifiers for addition or subtraction in analog calculators	<u>G06G 7/14</u>
Differential sense amplifiers	<u>G11C 7/062</u>
Logic comparators	H03K 5/24
Optical receivers with offset control of the differential preamplifier	H04B 10/6933
Differential drivers	H04L 25/0272

Informative references

Attention is drawn to the following places, which may be of interest for search:

Gain control in emitter coupled or cascode amplifiers	H03G 1/0023
Tuned filters, switched capacitor networks	<u>H03H 7/12, H03H 19/004</u>

Special rules of classification

Pseudo differential amplifiers (see the "Glossary of terms" section above) are usually classified in H03F 3/4508, H03F 3/45179, H03F 3/45278, H03F 3/45376.

Furthermore, it is common practice at EPO, when classifying semiconductor differential amplifiers, to consider first the technology of the amplifying transistors and the circuit topology information, in order to classify under one of the subgroups belonging to $\frac{H03F}{3/45076}$.

About circuit topology, the expression "Complementary long tailed pairs having parallel inputs and being supplied in parallel" is present in the following subgroups:

H03F 3/45112

H03F 3/4521

H03F 3/45309

H03F 3/45408



As clarifying example the following circuit topology is shown:

Example of differential amplifier with complementary long tailed pairs having parallel inputs and being supplied in parallel: the first transistor pair (711,712) and the second transistor pair (721,722) constitute two complementary transistor pairs, which, together with the corresponding current sources (710,720) constitute long tail pairs (see the "Glossary of terms" section above), and wherein said pairs have parallel inputs (see the common input terminals (VinN, VinP) and are supplied in parallel (see the common supplies VDD, VSS), (drawing extracted from US2005040889).

Similar consideration applies to the expression "Complementary PI types having parallel inputs and being supplied in parallel", wherein the complementary transistor pairs are forming differential amplifiers of the PI type, (see the "Glossary of terms" section above), and which are classified in the following subgroups:

H03F 3/45125

H03F 3/45224

H03F 3/45322

H03F 3/45421

About the expression "Complementary long tailed pairs having parallel inputs and being supplied in series", which is present in the following subgroups:

H03F 3/45139

H03F 3/45237

H03F 3/45336

H03F 3/45434



As clarifying example the following circuit topology is shown:

Example of differential amplifier with complementary long tailed pairs having parallel inputs and being supplied in series: the first transistor pair (Q221,Q222) and the second transistor pair (Q223, Q224) constitute two complementary transistor pairs, which, together with the corresponding current sources (234,236) constitute long tail pairs (see the "Glossary of terms" section above), and wherein said pairs have parallel inputs (see the common input terminals (VIN-, VIN+) and are supplied in series (see the series connecting path from VD to GND, which is formed by element 234, the first transistor pair (Q221,Q222), the second transistor pair (Q223, Q224), element 236), (drawing extracted from FR2814554).

Similar consideration applies to the expression "Complementary PI types having parallel inputs and being supplied in series", wherein the complementary transistor pairs are forming differential amplifiers of the PI type, (see the "Glossary of terms" section above), and which are classified in the following subgroups:

H03F 3/45152

H03F 3/45251

H03F 3/45349

H03F 3/45448

Once that the technology and the circuit topology related to the differential amplifier are classified, a possible classification under one of the subgroups belonging to $\frac{H03F}{3/45479}$ has to be considered. It must be noted that the expression "common mode signal rejection", which is present in the definition of subgroup $\frac{H03F}{3/45479}$, has to be interpreted with a broader meaning than the one used in common practice (see the "Glossary of terms" section above). In practice common mode rejection has to be meant as operating point/DC level control/offset reduction, and said control can be implemented at sub-circuit level.

Hence all the subgroups of <u>H03F 3/45479</u> are addressing all the possible implementations of said common mode rejection within the sub-circuits that are forming the differential amplifier architecture (for a detailed definition of said sub-circuits see the following section).

Indexing Code orthogonal classification

In addition to one or more EC symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to orthogonal classification

(<u>H03F 2203/45002</u> - <u>H03F 2203/45732</u>), i.e. covering aspects which are spanning over one or more EC subgroups, should be allocated for this subgroup.

Said aspects are mainly based on the following sub-circuits, which can be determined in a long tailed pair, PI type, and, although with limitations, in special types of differential amplifiers, e.g. pseudo-differential amplifier:

AAC = Active Amplifying Circuit, i.e. the elements comprising the amplifying transistors.

CSC = Common Source Circuit, i.e. the elements forming the long tailed circuit or the PI circuit.

IC = Input Circuit, i.e. the elements coupled to the input terminals of the amplifying transistors.

LC = Loading Circuit, i.e. the elements coupled to the output terminals of the amplifying transistors.

CMCL = Common Mode Controlling Loop, i.e. the elements which are controlling the common mode(s) of the differential amplifier.

FBC = Feed-Back Circuit, i.e. the elements which are introducing feedback signal(s) for the differential amplifier.

Here is an example of some of said sub-circuits above for a long tailed differential pair.



drawing derived from US2006055463

H03F 3/46

Reflex amplifiers {(reflection amplifiers H03F 3/608)}

Definition statement

This place covers:

Reflex amplifiers, see the "Glossary of terms" section above, which are implemented via semiconductor elements or tubes.

Limiting references

This place does not cover:

Reflection amplifiers	H03F 3/608

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Receivers comprising at least one semiconductor device having three or	<u>H04B 1/24</u>
more electrodes	

H03F 3/50

Amplifiers in which input is applied to, or output is derived from, an impedance common to input and output circuits of the amplifying element, e.g. cathode follower

Definition statement

This place covers:

Amplifiers in cathode follower, source follower, emitter follower configuration (see the "Glossary of terms" section above).

References

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Delay circuits H03K 5/13

Special rules of classification

Indexing Code deep-indexing classification

In addition to one or more classification symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to deep-indexing classification (<u>H03F 2203/5003</u> - <u>H03F 2203/5045</u>), i.e. covering embodiment aspects, should be allocated for this subgroup.

H03F 3/54

Amplifiers using transit-time effect in tubes or semiconductor devices (parametric amplifiers H03F 7/00; solid state travelling-wave devices H01L 45/02)

Definition statement

This place covers:

Amplifiers using transit-time effects, mostly Klystrons or Travelling Wave Tubes (TWT) see the "Glossary of terms" section above.

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

|--|

Informative references

Attention is drawn to the following places, which may be of interest for search:

Parametric amplifiers	H03F 7/00
Travelling wave tubes in general	<u>H01J 25/34</u>
Resonators of the waveguide type	<u>H01P 7/00</u>

H03F 3/60

Amplifiers in which coupling networks have distributed constants, e.g. with waveguide resonators (H03F 3/54 takes precedence)

Definition statement

This place covers:

Amplifiers having distributed coupling networks, e.g. transmission lines, the so called microwave amplifiers.

References

Limiting references

This place does not cover:

Amplifiers using transit-time effect, e.g. TWTA	<u>H03F 3/54</u>
Parametric amplifiers	H03F 7/00

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Class E amplifiers	H03F 3/2176
Reflex amplifiers	<u>H03F 3/46</u>
Multi-channel amplifiers	H03F 3/68
Aerials or aerial systems providing at least two radiating patterns, beam- forming means	<u>H01Q 25/00, H01Q 3/40</u>

Informative references

Attention is drawn to the following places, which may be of interest for search:

Modification of amplifiers by use of distributed coupling, i.e. distributed lumped elements	<u>H03F 1/18</u>
Amplifiers having more than three electrodes with field-effect devices	<u>H03F 3/16</u>

High frequency amplifiers	H03F 3/189
High frequency adaptations of semiconductors	<u>H01L 23/66</u>
Coupling devices of the waveguide type	<u>H01P 5/00</u>

H03F 3/62

Two-way amplifiers

Definition statement

This place covers:

Two-way amplifiers, which are implemented via semiconductor elements or tubes and which are typically employed to amplify the signal levels of forward and reverse signals.

References

Informative references

Attention is drawn to the following places, which may be of interest for search:

Multiport networks	<u>H03H 7/48</u>
Hybrid arrangements for transceivers	<u>H04B 1/58</u>
Intermediate station arrangements for frequency-division multiplex systems	<u>H04J 1/10, H04J 1/10</u>

H03F 3/66

Amplifiers simultaneously generating oscillations of one frequency and amplifying signals of another frequency

Definition statement

This place covers:

Amplifying-mixing devices for achieving a special technical effect, e.g. interference reduction.

References

Informative references

Attention is drawn to the following places, which may be of interest for search:

Modifications of amplifiers to reduce non-linear distortion	H03F 1/32
Transference of modulation from one carrier to another	H03D 7/00

H03F 3/68

Combinations of amplifiers, e.g. multi-channel amplifiers for stereophonics {(power amplifiers using a combination of several semiconductor amplifiers H03F 3/211; combinations of amplifiers using coupling networks with distributed constants H03F 3/602)}

Definition statement

This place covers:

Stereo amplifiers or multi-channel amplifiers in the low frequency range.

Multi-band amplifiers in the high frequency range, wherein multiple outputs are present.

References

Limiting references

This place does not cover:

Aerials, beam-forming means	<u>H01Q 25/00, H01Q 3/40</u>
Circuits for stereophonic arrangements	H04R 5/04

Informative references

Attention is drawn to the following places, which may be of interest for search:

Low frequency amplifiers	H03F 3/181
Power amplifiers using a combination of several semiconductor amplifiers	<u>H03F 3/211</u>
Switching amplifiers	H03F 3/217
Combinations of amplifiers using coupling networks with distributed constants	<u>H03F 3/602</u>

H03F 3/70

Charge amplifiers

Definition statement

This place covers:

Charge amplifiers, see the "Glossary of terms" section above.

References

Limiting references

This place does not cover:

Charge pumps for DC/DC power converters	<u>H02M 3/07</u>
Charge pumps for automatic control of frequency or phase circuits	H03L 7/0891

Application-oriented references

Examples of places where the subject matter of this place is covered when specially adapted, used for a particular purpose, or incorporated in a larger system:

Measuring acceleration by piezo-electric pick-up	<u>G01P 15/09</u>
Integrators using operational amplifier and capacitor and resistor in the feedback loop	<u>G06G 7/186</u>
Sense amplifiers	<u>G11C 7/06</u>

H03F 3/72

Gated amplifiers, i.e. amplifiers which are rendered operative or inoperative by means of a control signal

Definition statement

This place covers:

Amplifiers which are enabled or disabled by means of a control signal, e.g. via a controlled switch.

References

Informative references

Attention is drawn to the following places, which may be of interest for search:

Gain control in amplifiers	<u>H03G 3/00</u>
Electronic switching or gating	<u>H03K 17/00</u>

Special rules of classification

Indexing Code deep-indexing classification

In addition to one or more classification symbols relating to the invention information, where appropriate, one or more Indexing Code symbols relating to deep-indexing classification (<u>H03F 2203/7203</u> - <u>H03F 2203/7239</u>), i.e. covering embodiment aspects, should be allocated for this subgroup.

H03F 7/00

Parametric amplifiers ({H03F 19/00 takes precedence}; devices or arrangements for the parametric generation or amplification of light, infra-red or ultra-violet waves G02F 1/39)

Definition statement

This place covers:

Parametric amplifiers, i.e., wherein a component parameter such as capacitance or inductance is varied to achieve amplification. .

H03F 7/02

using variable-inductance element; using variable-permeability element

Definition statement

This place covers:

Parametric amplifiers where inductance/permeability is varied to achieve amplification.

H03F 7/04

using variable-capacitance element; using variable-permittivity element

Definition statement

This place covers: Parametric amplifiers where capacitance/permittivity is varied to achieve amplification.

H03F 9/00

Magnetic amplifiers

Definition statement

This place covers: Amplifiers using saturable reactors as amplifying elements (aka mag-amps).

H03F 9/02

current-controlled, i.e. the load current flowing in both directions through a main coil

Definition statement

This place covers:

Magnetic amplifiers where an AC load current flows in a main coil, controlled by the current in a control coil.

H03F 9/04

voltage-controlled, i.e. the load current flowing in only one direction through a main coil, e.g. Logan circuits (<u>H03F 9/06</u> takes precedence)

Definition statement

This place covers:

Magnetic amplifiers where a load current flows in one direction in a main coil, and typically in the other direction in another main coil, controlled by the current in a control coil, e.g., a control coil in a center leg of a transformer controlling two main coils in two outer legs.

H03F 9/06

Control by voltage time integral, i.e. the load current flowing in only one direction through a main coil, whereby the main coil winding also can be used as a control winding, e.g. Ramey circuits

Definition statement

This place covers:

Magnetic amplifiers where the load current is auto-commutated by the main coil, the core being periodically reset by a control coil.

H03F 11/00

Dielectric amplifiers

Definition statement

This place covers:

Amplifiers using non-linear (hysteretic) dielectric elements to achieve amplification.

H03F 13/00

Amplifiers using amplifying element consisting of two mechanically- or acoustically-coupled transducers, e.g. telephone-microphone amplifier

Definition statement

This place covers: Amplifiers with intermediate mechanical or acoustic energy transfer.

H03F 15/00

Amplifiers using galvano-magnetic effects not involving mechanical movement, e.g. using Hall effect

Definition statement

This place covers:

Amplifiers relying on galvano-magnetic effects, i.e., which arise when a conductor or semiconductor placed in a magnetic field carries current, such as the Hall-effect.

H03F 17/00

Amplifiers using electroluminescent element or photocell

Definition statement

This place covers:

Amplifiers relying on intermediate transformation into light to achieve amplification.

Limiting references

This place does not cover:

Amplifiers controlled by light, e.g., for fiber optic links	<u>H03F 3/08</u>
Amplifiers with optical coupling between stages	H03F 3/085

H03F 21/00

{Amplifiers not covered by groups <u>H03F 3/00</u> - <u>H03F 19/00</u> (dynamo-electric amplifiers <u>H02K</u>)}

Definition statement

This place covers:

Amplifiers not covered elsewhere, e.g., relying on radioactivity, or using esoteric semiconductor structures.